<u>RFHIC</u>

Product Features

- GaN on SiC Chip on Board
- Surface Mount Hybrid Type
- Asymmetric Doherty Amplifier
- High Efficiency
- No Matching circuit needed

Applications

- RF Sub-Systems
- Base Station
- RRH
- 4G/ LTE system
- Small cell



Description

Accommodating the future of 4G/LTE small cells, RFHIC introduces RTH20007-10 amplifier fabricated using an advanced high power density Gallium Nitride (GaN) semiconductor process. This high performance amplifier achieves high efficiency of 45%, and powers 7W over the frequency range from 1930MHz to 1990MHz. Integrated with Asymmetrical Doherty configurations, RTH Series is packaged in a very small form-factor 28 x 19 x 4.8mm on AIN (aluminum nitride) board which provides excellent thermal dissipation.

Electrical Specifications @ Vds =31V, Ta=25 °C

| PARAMETER | UNIT | MIN | ТҮР | MAX | CONDITION |
|-------------------|------|------|------|------|---------------------------|
| Frequency Range | MHz | 1930 | - | 1990 | ZS = ZL = 50 ohm |
| Power Gain | | 13.5 | 15.5 | - | |
| Gain Flatness | dB | -3.0 | - | 3.0 | Carrier Idq = 160mA |
| Input Return Loss | | -6 | -9 | - | Vgp = -4.8V |
| Pout @ Average | dBm | - | 38.5 | - | |
| Pout @ Psat | dBm | 46 | 47 | - | Pulse Width=20us, Duty10% |
| ACLR @ BW 10MHz | dBc | - | -27 | - | Non DPD |
| LTE (PAPR 7.5dB) | | - | -53 | - | With DPD |
| Drain Efficiency | % | 40 | 45 | - | |
| Carrier Idq | | - | 220 | - | Pout @ Average |
| Total Ids | mA | - | 500 | - | |
| | | - | -3.0 | -2.0 | Vgc |
| Supply Voltage | v | - | -5.0 | -4.0 | Vgp |
| | | 30.5 | 31 | - | Vds |

Caution

The drain voltage must be supplied to the device after the gate voltage is supplied

Turn on :Turn on the Gate voltage supply and last turn on the Drain voltage supplies Turn off :Turn off the Drain voltage and last turn off the Gate voltage

Note

1. ACLR Measured Pout=38.5dBm @ fc± 10MHz / 9.015MHz

LTE 10MHz 1FA PAPR=7.5dB @ 0.01% probability on CCDF, (DPD Engine: Optichron OP6180)

Mechanical Specifications

| PARAMETER | UNIT | ТҮР | REMARK |
|-----------|------|---------------|--------|
| Mass | g | 5 | - |
| Dimension | mm | 28 x 19 x 4.8 | - |

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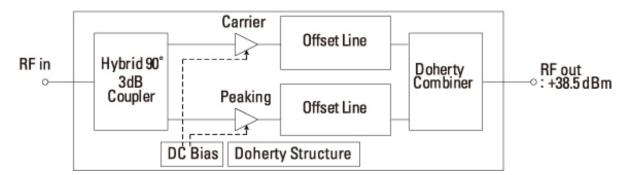
Absolute Maximum Ratings

| PARAMETER | UNIT | RATING | SYMBOL |
|--------------------------------|------|-----------|------------------|
| Gate-Source Voltage | V | -10 ~ 0 | Vgc Vgp |
| Drain-Source Voltage | V | 50 | Vds |
| Gate Current | mA | 4.0 | Igs |
| Operating Junction Temperature | °C | 225 | T _J |
| Operating Case Temperature | °C | -30 ~ 85 | T _C |
| Storage Temperature | °C | -40 ~ 100 | T _{STG} |

Operating Voltages

| PARAMETER | UNIT | MIN | ТҮР | MAX | SYMBOL |
|--------------------------|------|------|------------------|-----|--------|
| Drain Voltage | V | 30.5 | 31 | - | Vds |
| Gate Voltage (on-stage) | V | - | Vgc @Carrier Idq | -2 | Vgc |
| Gate Voltage (on-stage) | V | - | Vgp | -2 | Vgp |
| Gate Voltage (off-stage) | V | - | -8 | - | Vgc |
| Gate Voltage (off-stage) | V | - | -8 | - | Vgp |

Block Diagram

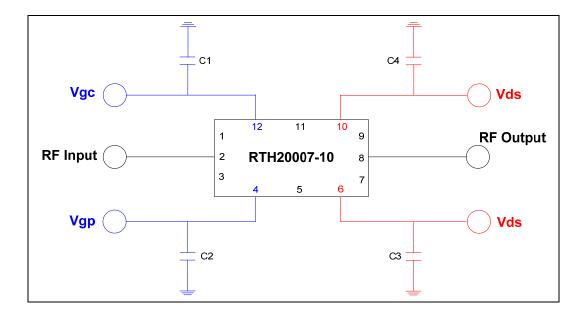


*Note

Directional coupler, isolator and drive amplifier MUST be located CLOSE to the DUT(device under test) is needed for best performance.



Application Circuit



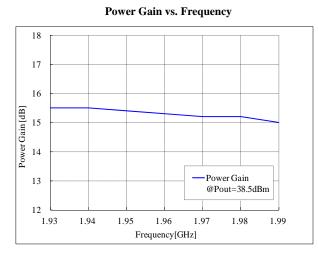
Part List

| Location | Model No. | Spec. | Maker | |
|------------------|----------------|---------------|--------|--|
| C3, C4 | 1812C225K101CT | 2.2uF / 100V | WALSIN | |
| C1, C2 | C3216X7R1C106K | 10uF / 16V | TDK | |
| Evaluation Board | RO4350B | 2Layer, 30mil | ROGERS | |

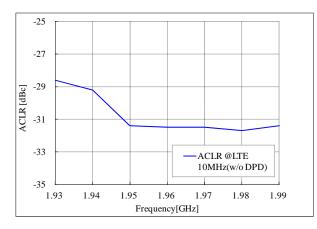
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Performance Charts

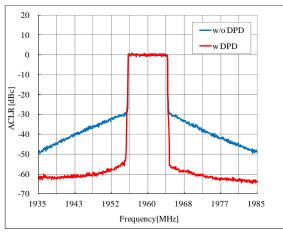
* Bias condition @ Carrier Idq= 160mA, Vgp= 4.8V, Ta=25 $^\circ\!\!\mathbb{C}$

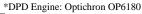


ACLR vs. Frequency



ACLR with Digital Predistortion

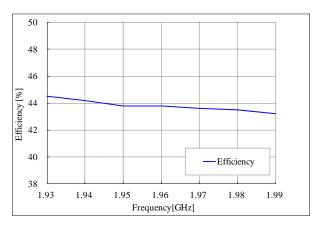


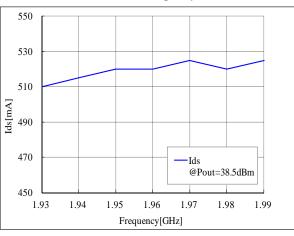


50 49 48 Psat [dBm] 47 46 Psat @Pulse Width 45 20us (Duty 10%) 44 1.94 1.98 1.99 1.93 1.95 1.96 1.97 Frequency[GHz]

Psat vs. Frequency

Drain Efficiency vs. Frequency



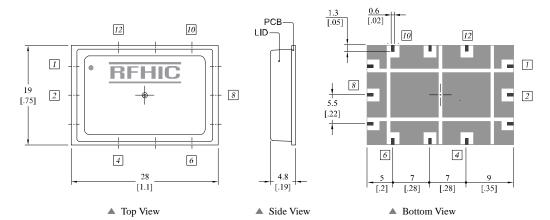


Ids vs. Frequency

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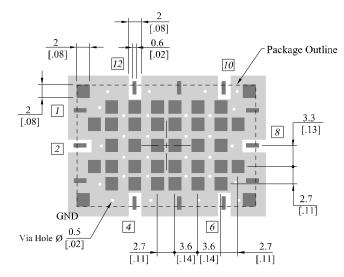
Package Dimensions (Type: NP-8CL)

* Unit: mm[inch] | Tolerance: ±0.15[.008]

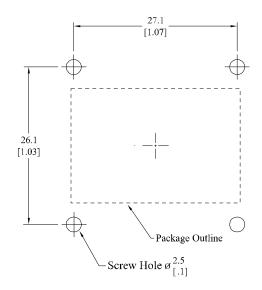


| Pin Description | | | | | | | | |
|-----------------|----------|--------|--------|----------|-----------|----|-----|--|
| Pin No | Function | Pin No | Pin No | Function | | | | |
| 1 | GND | 4 | Vgp | 7 | GND | 10 | Vds | |
| 2 | RF Input | 5 | GND | 8 | RF Output | 11 | GND | |
| 3 | GND | 6 | Vds | 9 | GND | 12 | Vgc | |

Recommended Pattern



Recommended Mounting Configuration



* Mounting Configuration Notes

1. For the proper performance of the device, Ground / Thermal via holes must be designed to remove heat.

2. To properly use heatsink, ensure the ground/thermal via hole region to contact the heatsink. We recommend the mounting screws

be added near the heatsink to mount the board

3. In designing the necessary RF trace, width will depend upon the PCB material and construction.

4. Use 1 oz. Copper minimum thickness for the heatsink.

5. Do not put solder mask on the backside of the PCB in the region where the board contacts the heatsink

6. We recommend adding as much copper as possible to inner and outer layers near the part to ensure optimal thermal performance.



Precautions

This product is a Gallium Nitride Transistor.

The Gallium Nitride Transistor requires a Negative Voltage Bias which operates alongside a Positive Voltage Bias. These Biases are applied in accordance to the Sequence during Turn-On and Turn-Off.

The Pallet Amplifier does not have a built-in Bias Sequence Circuit. Therefore, users need to either apply positive voltages and negative voltages in the required sequence, or add an external Bias Circuit to this Amplifier.

The required sequence for power supply is as follows.

During Turn-On

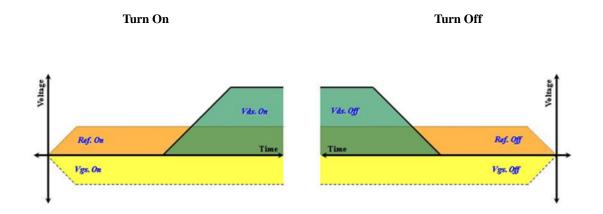
- 1. Connect GND.
- 2. Apply Gate Voltage (Vgc and Vgp)
- 3. Apply Drain Voltage (Vds)
- 4. Apply the RF Power.

During Turn-Off

1. Turn off RF power.

2. Turn off Drain Voltage (Vds), and then, turn off the Gate Voltage (Vgc and Vgp) $\,$

3. Remove all connections.



- Sequence Timing Diagram -

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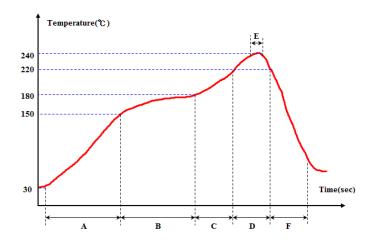
Reflow Profile

* Reflow oven settings

| Zone | Α | В | С | D | Е | F |
|-----------------|--------------|--------------------|-------------|--------------------|--------------|------------------------|
| Temperature(°C) | 30∼150 °C | 150 ~ 180 ℃ | 180∼220 °C | 220 ~ 220 ℃ | 235 ~ 240 °C | $2 \sim 6$ °C/Sec Drop |
| Belt speed | 55 ~ 115 sec | 55 ~ 75 sec | 30 ~ 50 sec | 30 ~ 50 sec | 5 ~ 10 sec | 60 ~ 90 sec |

Reflow Cycle Limit= 1time

* Measured reflow profile



Ordering Information

| Part Number | Package Design | |
|-------------|-------------------------|--|
| | -R (Reel) | |
| RTH20007-10 | -B (Bulk) | |
| | -EVB (Evaluation Board) | |

Revision History

| Part Number | Release Date | Version | Modification | Data Sheet Status |
|-------------|--------------|---------|--------------------------------|-------------------|
| RTH20007-10 | 2013.11.15 | 1.0 | Electrical specifications (1p) | - |
| RTH20007-10 | 2013.02.25 | 0.5 | Package Dimension | Preliminary |
| RTH20007-10 | 2013.01.15 | 0.3 | Application circuit | Preliminary |

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